December 2023 / Vol. 184 Mitsubishi Electric

ADVANCE

High Frequency & Optical Devices

Editorial-Chief

Masahiro Otani

Editorial Advisors

Kenichiro Kurahashi Hisao Takahashi Omi Kuriwaki Asuka Omori Hiroyuki Teranishi Satoshi Watanabe Kenichi Uto Tsutomu Matsubara Yasumasa Yamanaga Takao Ikai Kunihiko Egawa Hideya Tadokoro Kenji Okuma Yusuke Hirata Satoru Yamaguchi Yoshihiro Yamaguchi

• Vol. 184 Feature Articles Editor

Yoshihisa Tashiro

Kohei Miki

Editorial Inquiries

Masahiro Otani Corporate Productivity Engineering & Logistics Dept.

Fax: +81-3-3218-2465

Mitsubishi Electric Advance is published on line quarterly (in March, June, September, and December) by Mitsubishi Electric Corporation. Copyright © 2023 by Mitsubishi Electric Corporation; all rights reserved. Printed in Japan.

The company names and product names described herein are the trademarks or registered trademarks of the respective companies.

CONTENTS

Overview	1
Technical Reports	
10W Class, Wideband GaN Power Amplifier Module for 5G Base – Stations	2
Wider – temperature – range CWDM 100Gbps EML Chip for Data Centers	7
50Gbps DFB Laser Diode for 5G Base Stations	0
1.55µm Tunable DFB-LD for 400G Digital Coherent Optical Transmission System	3
Thermal Diode Infrared Sensor "MelDIR" and User Support Tools	6

Precis

Digital transformation (DX) advances innovation in business activities and transformation in lifestyles, so the importance of communications infrastructure and sensor technology is rising. In this issue, we introduce highly efficient GaN amplifiers and high-speed optical devices for the latest information communications, as well as infrared sensor modules required in applications in the areas of crime prevention and surveillance.